CS51031

Fast P-Ch FET Buck Controller

The CS51031 is a switching controller for use in DC−DC converters. It can be used in the buck topology with a minimum number of external components. The CS51031 consists of a V_{CC} monitor for controlling the state of the device, 1.0 A power driver for controlling the gate of a discrete P−Channel transistor, fixed frequency oscillator, short circuit protection timer, programmable Soft−Start, precision reference, fast output voltage monitoring comparator, and output stage driver logic with latch.

The high frequency oscillator allows the use of small inductors and output capacitors, minimizing PC board area and systems cost. The programmable Soft−Start reduces current surges at startup. The short circuit protection timer significantly reduces the duty cycle to approximately 1/30 of its cycle during short circuit conditions.

Features

- 1.0 A Totem Pole Output Driver
- High Speed Oscillator (700 kHz max)
- No Stability Compensation Required
- Lossless Short Circuit Protection
- V_{CC} Monitor
- 2.0% Precision Reference
- Programmable Soft−Start
- Wide Ambient Temperature Range:
  - Industrial Grade: −40°C to 85°C
  - Commercial Grade: 0°C to 70°C
- Pb−Free Packages are Available

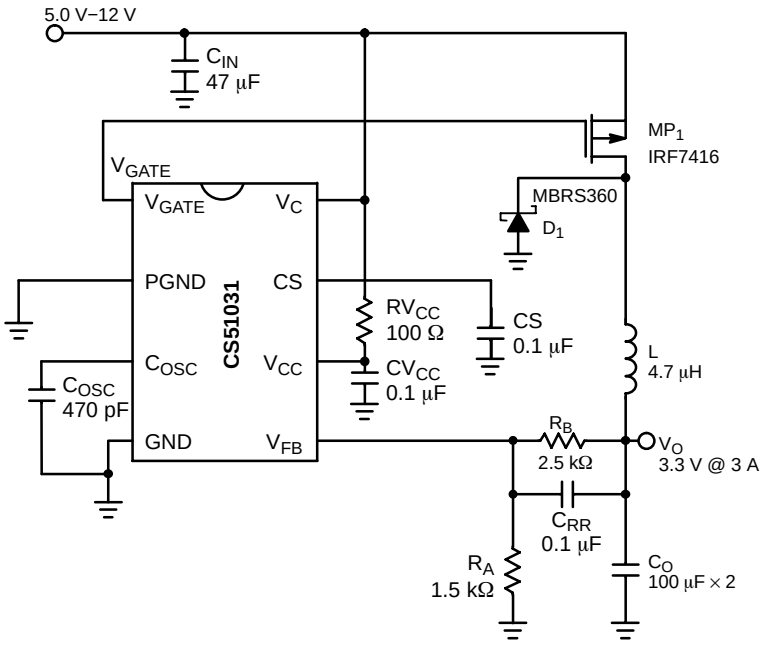


Figure 1. Typical Application Diagram

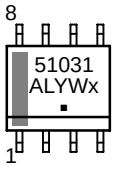
ON Semiconductor®

http://onsemi.com



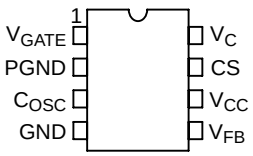
SOIC−8
D SUFFIX
CASE 751

MARKING DIAGRAM



51031 = Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
x = Continuation of Device Code
x = Y or G
▪ = Pb−Free Package

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

© Semiconductor Components Industries, LLC, 2005

ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping†
CS51031YD8	−40°C < T_A < 85°C	SOIC−8	98 Units / Rail
CS51031YD8G		SOIC−8 (Pb−Free)	98 Units / Rail
CS51031YDR8		SOIC−8	2500 / Tape & Reel
CS51031YDR8G		SOIC−8 (Pb−Free)	2500 / Tape & Reel
CS51031GD8	0°C < T_A < 70°C	SOIC−8	98 Units / Rail
CS51031GD8G		SOIC−8 (Pb−Free)	98 Units / Rail
CS51031GDR8		SOIC−8	2500 / Tape & Reel
CS51031GDR8G		SOIC−8 (Pb−Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating		Value	Unit
Power Supply Voltage, V_{CC}		20	V
Driver Supply Voltage, V_C		20	V
Driver Output Voltage, V_{GATE}		20	V
C_{OSC}, CS, V_{FB} (Logic Pins)		6.0	V
Peak Output Current		1.0	A
Steady State Output Current		200	mA
Operating Junction Temperature, T_J		150	°C
Operating Temperature Range, T_A		−40 to 85	°C
Storage Temperature Range, T_S		−65 to 150	°C
ESD (Human Body Model)		2.0	kV
Lead Temperature Soldering:	Wave Solder: (through hole styles only) (Note 1) Reflow (SMD styles only) (Note 2)	260 peak 230 peak	°C °C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. 10 sec. maximum.
2. 60 sec. max above 183°C.

PACKAGE LEAD DESCRIPTION

Package Pin Number	Pin Symbol	Function
1	V_{GATE}	Driver pin to gate of external P−Ch FET.
2	PGND	Output power stage ground connection.
3	C_{OSC}	Oscillator frequency programming capacitor.
4	GND	Logic ground.
5	V_{FB}	Feedback voltage input.
6	V_{CC}	Logic supply voltage.
7	CS	Soft−Start and fault timing capacitor.
8	V_C	Driver supply voltage.

ELECTRICAL CHARACTERISTICS (Specifications apply for $4.5 \le V_{CC} \le 16$ V, $3.0\ V \le V_C \le 16$ V; Industrial Grade: $-40°C < T_A < 85°C$; $-40°C < T_J < 125°C$: Commercial Grade: $0°C < T_A < 70°C$; $0°C < T_J < 125°C$, unless otherwise specified.)

Characteristic	Test Conditions	Min	Typ	Max	Unit
Oscillator	**V_{FB} = 1.2 V**				
Frequency	C_{OSC} = 470 pF	160	200	240	kHz
Charge Current	1.4 V < V_{COSC} < 2.0 V	−	110	−	μA
Discharge Current	2.7 V > V_{COSC} > 2.0 V	−	660	−	μA
Maximum Duty Cycle	1 − (t_{OFF}/t_{ON})	80.0	83.3	−	%
Short Circuit Timer	**V_{FB} = 1.0 V; CS = 0.1 μF; V_{COSC} = 2.0 V**				
Charge Current	1.0 V < V_{CS} < 2.0 V	175	264	325	μA
Fast Discharge Current	2.55 V > V_{CS} > 2.4 V	40	66	80	μA
Slow Discharge Current	2.4 V > V_{CS} > 1.5 V	4.0	6.0	10	μA
Start Fault Inhibit Time	0 V < V_{CS} < 2.5 V	0.70	0.85	1.40	ms
Valid Fault Time	2.6 V > V_{CS} > 2.4 V	0.2	0.3	0.45	ms
GATE Inhibit Time	2.4 V > V_{CS} > 1.5 V	9.0	15	23	ms
Fault Duty Cycle	−	2.5	3.1	4.6	%
CS Comparator	**V_{FB} = 1.0 V**				
Fault Enable CS Voltage	−	−	2.5	−	V
Max CS Voltage	V_{FB} = 1.5 V	−	2.6	−	V
Fault Detect Voltage	V_{CS} when GATE goes high	−	2.4	−	V
Fault Inhibit Voltage	Minimum V_{CS}	−	1.5	−	V
Hold Off Release Voltage	V_{FB} = 0 V	0.4	0.7	1.0	V
Regulator Threshold Voltage Clamp	V_{CS} = 1.5 V	0.725	0.866	1.035	V
V_{FB} Comparators	**V_{COSC} = V_{CS} = 2.0 V**				
Regulator Threshold Voltage	T_J = 25°C (Note 3) T_J = −40 to 125°C	1.225 1.210	1.250 1.250	1.275 1.290	V V
Fault Threshold Voltage	T_J = 25°C (Note 3) T_J = −40 to 125°C	1.12 1.10	1.15 1.15	1.17 1.19	V V
Threshold Line Regulation	$4.5\ V \le V_{CC} \le 16$ V	−	6.0	15	mV
Input Bias Current	V_{FB} = 0 V	−	1.0	4.0	μA
Voltage Tracking	(Regulator Threshold − Fault Threshold Voltage)	70	100	120	mV
Input Hysteresis Voltage	−	−	4.0	20	mV
Power Stage	**V_{CC} = V_C = 10 V; V_{FB} = 1.2 V**				
GATE DC Low Saturation Voltage	V_{COSC} = 1.0 V; 200 mA Sink	−	1.2	1.5	V
GATE DC High Saturation Voltage	V_{COSC} = 2.7 V; 200 mA Source; $V_C = V_{GATE}$	−	1.5	2.1	V
Rise Time	C_{GATE} = 1.0 nF; 1.5 V < V_{GATE} < 9.0 V	−	25	60	ns
Fall Time	C_{GATE} = 1.0 nF; 9.0 V > V_{GATE} > 1.5 V	−	25	60	ns
V_{CC} Monitor					
Turn−On Threshold	−	4.200	4.400	4.600	V
Turn−Off Threshold	−	4.085	4.300	4.515	V
Hysteresis	−	65	130	200	mV
Current Drain					
I_{CC}	4.5 V < V_{CC} < 16 V, Gate switching	−	4.5	6.0	mA
I_C	3.0 V < V_C < 16 V, Gate non−switching	−	2.7	4.0	mA
Shutdown I_{CC}	V_{CC} = 4.0	−	500	900	μA

3. Guaranteed by design, not 100% tested in production.

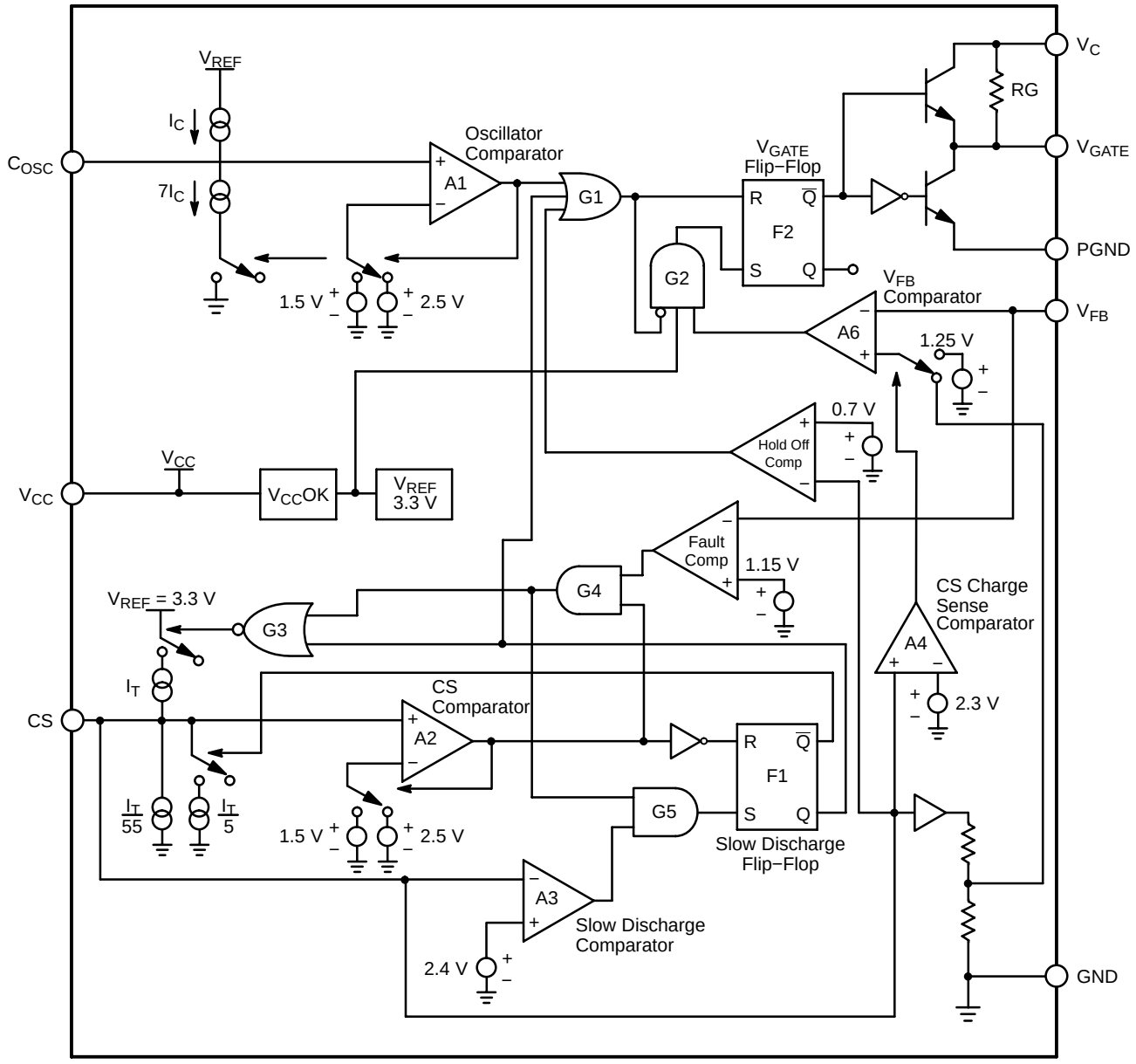


Figure 2. Block Diagram

CIRCUIT DESCRIPTION

THEORY OF OPERATION

Control Scheme

The CS51031 monitors the output voltage to determine when to turn on the P−Ch FET. If V_{FB} falls below the internal reference voltage of 1.25 V during the oscillator's charge cycle, the P−Ch FET is turned on and remains on for the duration of the charge time. The P−Ch FET gets turned off and remains off during the oscillator's discharge time with the maximum duty cycle to 80%. It requires 7.0 mV typical, and 20 mV maximum ripple on the V_{FB} pin is required to operate. This method of control does not require any loop stability compensation.

Startup

The CS51031 has an externally programmable Soft−Start feature that allows the output voltage to come up slowly, preventing voltage overshoot on the output.

At startup, the voltage on all pins is zero. As V_{CC} rises, the V_C voltage along with the internal resistor R_G keeps the P−Ch FET off. As V_{CC} and V_C continue to rise, the oscillator capacitor (C_{OSC}) and the Soft−Start/Fault Timing capacitor (CS) charges via internal current sources. C_{OSC} gets charged by the current source IC and CS gets charged by the I_T source combination described by:

$$I_{CS} = I_T - \left(\frac{I_T}{55} + \frac{I_T}{5}\right)$$

The internal Holdoff Comparator ensures that the external P−Ch FET is off until V_{CS} > 0.7 V, preventing the GATE flip−flop (F2) from being set. This allows the oscillator to reach its operating frequency before enabling the drive output. Soft−Start is obtained by clamping the V_{FB} comparator's (A6) reference input to approximately 1/2 of the voltage at the CS pin during startup, permitting the control loop and the output voltage to slowly increase. Once the CS pin charges above the Holdoff Comparator trip point of 0.7 V, the low feedback to the V_{FB} Comparator sets the GATE flip−flop during C_{OSC}'s charge cycle. Once the GATE flip−flop is set, V_{GATE} goes low and turns on the P−Ch FET. When V_{CS} exceeds 2.3 V, the CS charge sense comparator (A4) sets the V_{FB} comparator reference to 1.25 V completing the startup cycle.

Lossless Short Circuit Protection

The CS51031 has "lossless" short circuit protection since there is no current sense resistor required. When the voltage at the CS pin (the fault timing capacitor voltage) reaches 2.5 V during startup, the fault timing circuitry is enabled by A2. During normal operation the CS voltage is 2.6 V. During a short circuit or a transient condition, the output voltage moves lower and the voltage at V_{FB} drops. If V_{FB} drops below 1.15 V, the output of the fault comparator goes high and the CS51031 goes into a fast discharge mode. The fault timing capacitor, CS, discharges to 2.4 V. If the V_{FB} voltage is still below 1.15 V when the CS pin reaches 2.4 V, a valid fault condition has been detected. The slow discharge comparator output goes high and enables gate G5 which sets the slow discharge flip−flop. The V_{GATE} flip−flop resets and the output switch is turned off. The fault timing capacitor is slowly discharged to 1.5 V. The CS51031 then enters a normal startup routine. If the fault is still present when the fault timing capacitor voltage reaches 2.5 V, the fast and slow discharge cycles repeat as shown in figure 3.

If the V_{FB} voltage is above 1.15 V when CS reaches 2.4 V a fault condition is not detected, normal operation resumes and CS charges back to 2.6 V. This reduces the chance of erroneously detecting a load transient as a fault condition.

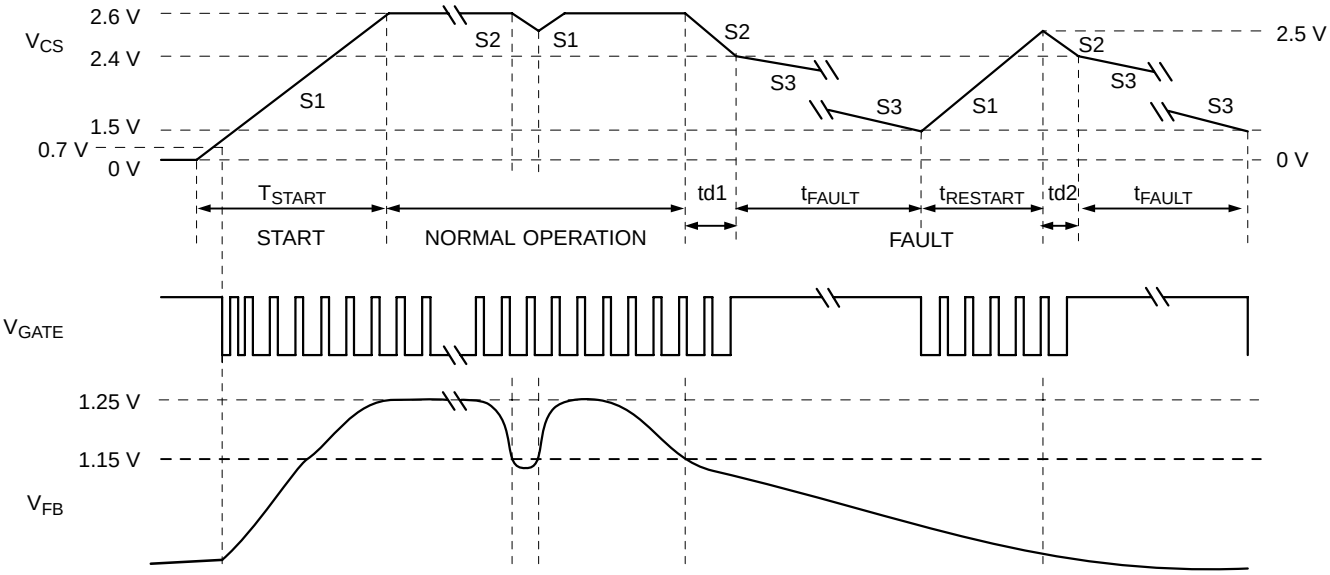


Figure 3. Voltage on Start Capacitor (V_{GS}), the Gate (V_{GATE}), and in the Feedback Loop (V_{FB}), During Startup, Normal and Fault Conditions

Buck Regulator Operation

A block diagram of a typical buck regulator is shown in Figure 4. If we assume that the output transistor is initially off, and the system is in discontinuous operation, the inductor current I_L is zero and the output voltage is at its nominal value. The current drawn by the load is supplied by the output capacitor C_O. When the voltage across C_O drops below the threshold established by the feedback resistors R1 and R2 and the reference voltage V_{REF}, the power transistor Q1 switches on and current flows through the inductor to the output. The inductor current rises at a rate determined by $(V_{IN} - V_{OUT})/L$. The duty cycle (or "on" time) for the CS51031 is limited to 80%. If output voltage remains higher than nominal during the entire C_{OSC} change time, the Q1 does not turn on, skipping the pulse.

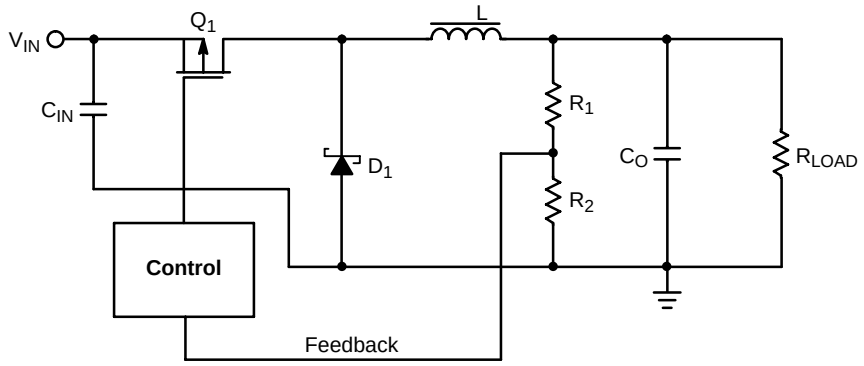


Figure 4. Buck Regulator Block Diagram

APPLICATIONS INFORMATION

CS51031 DESIGN EXAMPLE

Specifications 12 V to 5.0 V, 3.0 A Buck Controller

- V_{IN} = 12 V ±20% (i.e. 14.4 V max, 12 V nom, 9.6 V min)
- V_{OUT} = 5.0 V ±2%
- I_{OUT} = 0.3 A to 3.0 A
- Output ripple voltage < 50 mV max
- Efficiency > 80%
- f_{SW} = 200 kHz

1) Duty Cycle Estimates

Since the maximum duty cycle D, of the CS51031 is limited to 80% min, it is necessary to estimate the duty cycle for the various input conditions over the complete operating range.

The duty cycle for a buck regulator operating in a continuous conduction mode is given by:

$$D = \frac{V_{OUT} + V_F}{V_{IN} - V_{SAT}}$$

where:

$V_{SAT} = R_{DS(ON)} \times I_{OUT}$ max and $R_{DS(ON)}$ is the value at T_J 100°C.

If V_F = 0.60 V and V_{SAT} = 0.60 V then the above equation becomes:

$$D_{MAX} = \frac{5.6}{9.0} = 0.62$$

$$D_{MIN} = \frac{5.6}{13.8} = 0.40$$

2) Switching Frequency and On and Off Time Calculations

Given that f_{SW} = 200 kHz and D_{MAX} = 0.80

$$T = \frac{1.0}{f_{SW}} = 5.0\ \mu s$$

$$T_{ON(max)} = T \times D_{MAX} = 5.0\ \mu s \times 0.62 \cong 3.0\ \mu s$$

$$T_{ON(min)} = T \times D_{MIN} = 5.0\ \mu s \times 0.40 \cong 2.0\ \mu s$$

$$T_{OFF(max)} = T_{ON(min)} = 5.0\ \mu s - 2.0\ \mu s = 3.0\ \mu s$$

3) Oscillator Capacitor Selection

The switching frequency is set by C_{OSC}, whose value is given by:

$$C_{OSC}\ \text{in pF} = \frac{95 \times 10^{+6}}{F_{SW}\left(1 + \frac{F_{SW}}{3 \times 10^6} - \left(\frac{30 \times 10^3}{F_{SW}}\right)^2\right)}$$

4) Inductor Selection

The inductor value is chosen for continuous mode operation down to 0.3 Amps.

The ripple current $\Delta I = 2 \times I_{OUT}min = 2 \times 0.3\ A = 0.6\ A$.

$$L_{min} = \frac{(V_{OUT} + V_D) \times T_{OFF(max)}}{\Delta I} = \frac{5.6\ V \times 3.0\ \mu s}{0.6\ A} = 28\ \mu H$$

This is the minimum value of inductor to keep the ripple current < 0.6 A during normal operation.

A smaller inductor will result in larger ripple current. Ripple current at a minimum off time is:

$$\Delta I = \frac{(V_{OUT} + V_F) \times T_{OFF(min)}}{L_{MIN}} = \frac{5.6\ V \times 2.0\ \mu s}{28\ \mu H} = 0.4\ A$$

The core must not saturate with the maximum expected current, here given by:

$$I_{MAX} = I_{OUT} + \Delta I/2 = 3.0\ A + 0.4\ A/2 = 3.2\ A$$

5) Output Capacitor

The output capacitor and the inductor form a low pass filter. The output capacitor should have a low ESL and ESR. Low impedance aluminum electrolytic, tantalum or organic semiconductor capacitors are a good choice for an output capacitor. Low impedance aluminum are less expensive. Solid tantalum chip capacitors are available from a number of suppliers and are the best choice for surface mount applications.

The output capacitor limits the output ripple voltage. The CS51031 needs a maximum of 20 mV of output ripple for the feedback comparator to change state. If we assume that all the inductor ripple current flows through the output capacitor and that it is an ideal capacitor (i.e. zero ESR), the minimum capacitance needed to limit the output ripple to 50 mV peak−to−peak is given by:

$$C = \frac{\Delta I}{8.0 \times f_{SW} \times \Delta V} = \frac{0.6\ A}{8.0 \times (200 \times 10^3 Hz) \times (50 \times 10^{-3}\ V)} = 7.5 \mu F$$

The minimum ESR needed to limit the output voltage ripple to 50 mV peak−to−peak is:

$$ESR = \frac{\Delta V}{\Delta I} = \frac{50 \times 10^{-3}}{0.6\ A} = 83\ m\Omega$$

The output capacitor should be chosen so that its ESR is less than 83 mΩ.

During the minimum off time, the ripple current is 0.4 A and the output voltage ripple will be:

$$\Delta V = ESR \times \Delta I = 83m\ \Omega \times 0.4 = 33\ mV$$

6) V_{FB} Divider

$$V_{OUT} = 1.25\ V\left(\frac{R1 + R2}{R2}\right) = 1.25\ V\left(\frac{R1}{R2} + 1.0\right)$$

The input bias current to the comparator is 4.0 μA. The resistor divider current should be considerably higher than this to ensure that there is sufficient bias current. If we choose the divider current to be at least 250 times the bias current this permits a divider current of 1.0 mA and simplifies the calculations.

$$\frac{5.0\ V}{1.0\ mA} = R1 + R2 = 5.0\ K\Omega$$

Let R2 = 1.0 K

Rearranging the divider equation gives:

$$R1 = R2\left(\frac{V_{OUT}}{1.25} - 1.0\right) = 1.0\ k\Omega\left(\frac{5.0\ V}{1.25} - 1.0\right) = 3.0\ k\Omega$$

7) Divider Bypass Capacitor C_{RR}

Since the feedback resistors divide the output voltage by a factor of 4.0, i.e. 5.0 V/1.25 V = 4.0, it follows that the output ripple is also divided by four. This would require that the output ripple be at least 60 mV (4.0 × 15 mV) to trip the feedback comparator. We use a capacitor C_{RR} to act as an AC short.

The ripple voltage frequency is equal to the switching frequency so we choose C_{RR} = 1.0 nF.

8) Soft−Start and Fault Timing Capacitor CS

CS performs several important functions. First it provides a delay time for load transients so that the IC does not enter a fault mode every time the load changes abruptly. Secondly it disables the fault circuitry during startup, it also provides Soft−Start by clamping the reference voltage during startup, allowing it to rise slowly, and, finally it controls the hiccup short circuit protection circuitry. This reduces the duty cycle to approximately 0.035 during short circuit conditions.

An important consideration in calculating CS is that it's voltage does not reach 2.5 V (the voltage at which the fault detect circuitry is enabled) before V_{FB} reaches 1.15 V otherwise the power supply will never start.

If the V_{FB} pin reaches 1.15 V, the fault timing comparator will discharge CS and the supply will not start. For the V_{FB} voltage to reach 1.15 V the output voltage must be at least 4 × 1.15 = 4.6 V.

If we choose an arbitrary startup time of 900 μs, the value of CS is:

$$t_{Startup} = \frac{CS \times 2.5\ V}{I_{Charge}}$$

$$CS_{min} = \frac{900\ \mu s \times 264\ \mu A}{2.5\ V} = 950\ nF \cong 0.1\ \mu F$$

The fault time is the sum of the slow discharge time the fast discharge time and the recharge time. It is dominated by the slow discharge time.

The first parameter is the slow discharge time, it is the time for the CS capacitor to discharge from 2.4 V to 1.5 V and is given by:

$$t_{SlowDischarge(t)} = \frac{CS \times (2.4\ V - 1.5\ V)}{I_{Discharge}}$$

where $I_{Discharge}$ is 6.0 μA typical.

$$t_{SlowDischarge(t)} = CS \times 1.5 \times 10^5$$

The fast discharge time occurs when a fault is first detected. The CS capacitor is discharged from 2.5 V to 2.4 V.

$$t_{FastDischarge(t)} = \frac{CS \times (2.5\ V - 2.4\ V)}{I_{FastDischarge}}$$

where $I_{FastDischarge}$ is 66 μA typical.

$$t_{FastDischarge(t)} = CS \times 1515$$

The recharge time is the time for CS to charge from 1.5 V to 2.5 V.

$$t_{Charge(t)} = \frac{CS \times (2.5\ V - 1.5\ V)}{I_{Charge}}$$

where I_{Charge} is 264 μA typical.

$$t_{Charge(t)} = CS \times 3787$$

The fault time is given by:

$$t_{Fault} = CS \times (3787 + 1515 + 1.5 \times 10^5)$$

$$t_{Fault} = CS \times (1.55 \times 10^5)$$

For this circuit

$$t_{Fault} = 0.1 \times 10^{-6} \times 1.55 \times 10^5 = 15.5\ \mu s$$

A larger value of CS will increase the fault time out time but will also increase the Soft−Start time.

9) Input Capacitor

The input capacitor reduces the peak currents drawn from the input supply and reduces the noise and ripple voltage on the V_{CC} and V_C pins. This capacitor must also ensure that the V_{CC} remains above the UVLO voltage in the event of an output short circuit. A low ESR capacitor of at least 100 μF is good. A ceramic surface mount capacitor should also be connected between V_{CC} and ground to filter high frequency noise.

10) MOSFET Selection

The CS51031 drives a P−Channel MOSFET. The V_{GATE} pin swings from GND to V_C. The type of P−Ch FET used depends on the operating conditions but for input voltages below 7.0 V a logic level FET should be used.

A P−Ch FET with a continuous drain current (I_D) rating greater than the maximum output current is required.

The Gate−to−Source voltage V_{GS} and the Drain−to Source Breakdown Voltage should be chosen based on the input supply voltage.

The power dissipation due to the conduction losses is given by:

$$P_D = I_{OUT}^2 \times R_{DS(ON)} \times D$$

where

$$R_{DS(ON)} \text{ is the value at } T_J = 100^\circ C$$

The power dissipation of the P−Ch FET due to the switching losses is given by:

$$P_D = 0.5 \times V_{IN} \times I_{OUT} \times (t_r) \times f_{SW}$$

where t_r = Rise Time.

11) Diode Selection

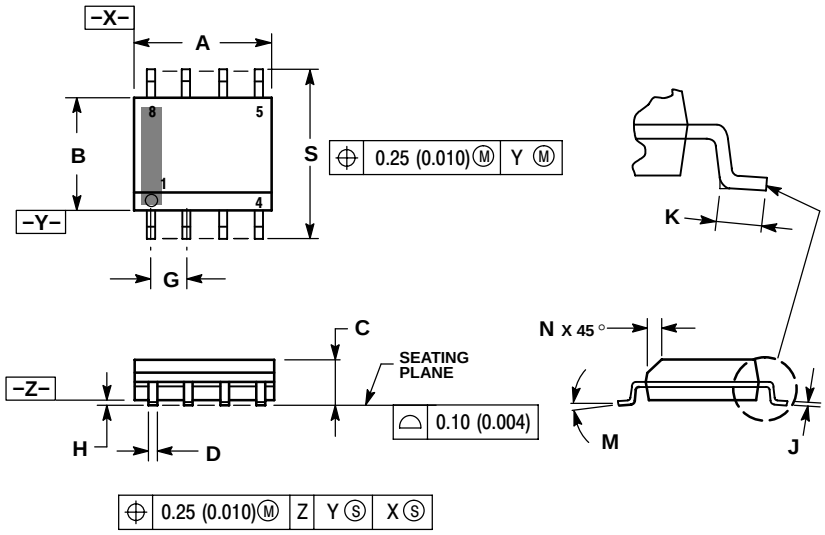
The flyback or catch diode should be a Schottky diode because of it's fast switching ability and low forward voltage drop. The current rating must be at least equal to the maximum output current. The breakdown voltage should be at least 20 V for this 12 V application.

The diode power dissipation is given by:

$$P_D = I_{OUT} \times V_D \times (1.0 - D_{min})$$

PACKAGE DIMENSIONS

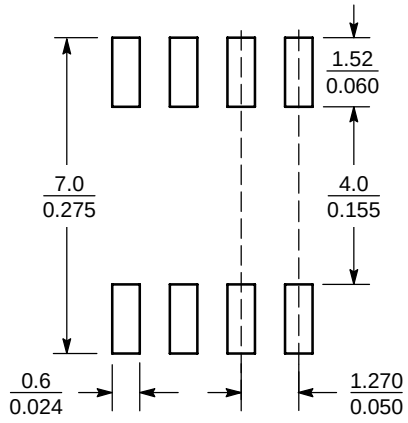
SOIC−8 NB
CASE 751−07
ISSUE AG



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751−01 THRU 751−06 ARE OBSOLETE. NEW STANDARD IS 751−07.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



SCALE 6:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE THERMAL DATA

Parameter		SOIC−8	Unit
$R_{\theta JC}$	Typical	45	°C/W
$R_{\theta JA}$	Typical	165	°C/W

ON Semiconductor and ON are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 61312, Phoenix, Arizona 85082−1312 USA
Phone: 480−829−7710 or 800−344−3860 Toll Free USA/Canada
Fax: 480−829−7709 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center
2−9−1 Kamimeguro, Meguro−ku, Tokyo, Japan 153−0051
Phone: 81−3−5773−3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:
moschip.ru
moschip.ru_4
moschip.ru_6
moschip.ru_9